Rev. 2 — 5 September 2011

Preliminary data sheet

1. Product profile

1.1 General description

Planar PIN diode in a SOD882 leadless ultra small plastic SMD package.

1.2 Features and benefits

- High speed switching for RF signals
- Low diode capacitance
- Low forward resistance
- Very low series inductance
- For applications up to 3 GHz

1.3 Applications

RF attenuators and switches

2. Pinning information

Table 1. Discrete pinning

Pin	Description	Simplified outline	Symbol
1	cathode	[1]	1.4
2	anode	1 2	sym006
		Transparent top view	

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 2. Ordering information

Type number	er Package			
	Name	Description	Version	
BAP55L	-	leadless ultra small plastic package; 2 terminals; body $1.0\times0.6\times0.5~\text{mm}$	SOD882	



4. Marking

Table 3. Marking

Type number	Marking code
BAP55L	E6

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{R}	reverse voltage		-	50	V
I _F	forward current		-	100	mA
P _{tot}	total power dissipation	T _s = 90 °C	-	500	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to soldering point		100	K/W

7. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 50 \text{ mA}$	-	0.95	1.1	V
I _R	reverse current	V _R = 20 V	-	-	10	nA
		V _R = 50 V	-	-	0.1	μΑ
C _d diode capacitance		f = 1 MHz; <u>Figure 2</u>				
		$V_R = 0 V$	-	0.27	-	pF
		V _R = 1 V	-	0.23	-	pF
		V _R = 20 V	-	0.18	0.28	pF
٠.	diode forward resistance	f = 100 MHz; <u>Figure 1</u>				
		$I_F = 0.5 \text{ mA}$	-	3.4	4.5	Ω
		I _F = 1 mA	-	2.3	3.3	Ω
		I _F = 10 mA	-	8.0	1.2	Ω
		I _F = 100 mA	-	0.4	0.7	Ω



 Table 6.
 Characteristics ...continued

 $T_j = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$ s_{12} ^2$	isolation	V _R = 0 V; <u>Figure 4</u>				
		f = 900 MHz	-	17.6	-	dB
		f = 1800 MHz	-	13	-	dB
		f = 2450 MHz	-	11.1	-	dB
$ s_{21} ^2$	insertion loss	I _F = 0.5 mA; <u>Figure 3</u>				
		f = 900 MHz	-	0.25	-	dB
		f = 1800 MHz	-	0.27	-	dB
		f = 2450 MHz	-	0.29	-	dB
		I _F = 1 mA; <u>Figure 3</u>				
		f = 900 MHz	-	0.17	-	dB
		f = 1800 MHz	-	0.19	-	dB
		f = 2450 MHz	-	0.21	-	dB
		I _F = 10 mA; <u>Figure 3</u>				
		f = 900 MHz	-	0.07	-	dB
		f = 1800 MHz	-	0.09	-	dB
		f = 2450 MHz	-	0.12	-	dB
		I _F = 100 mA; <u>Figure 3</u>				
		f = 900 MHz	-	0.05	-	dB
		f = 1800 MHz	-	0.07	-	dB
		f = 2450 MHz	-	0.09	-	dB
τ∟	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω ; measured at I_R = 3 mA	-	0.28	-	μS
L _S	series inductance		-	0.6	-	nΗ

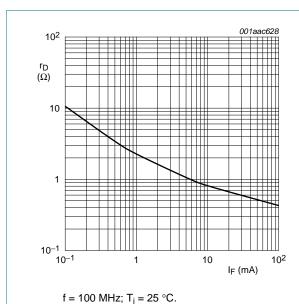
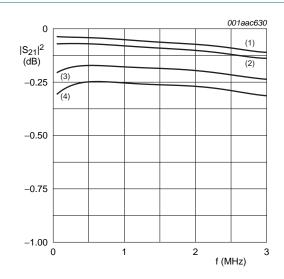


Fig 1. Forward resistance as a function of forward current; typical values

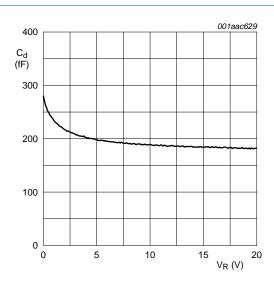


- (1) $I_F = 100 \text{ mA}.$
- (2) $I_F = 10 \text{ mA}.$
- (3) $I_F = 1 \text{ mA}.$
- (4) $I_F = 0.5 \text{ mA}.$

Diode inserted in series with a 50 Ω stripline circuit and biased via the analyzer Tee network.

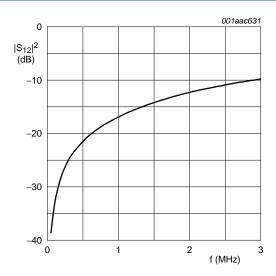
 $T_{amb} = 25 \, ^{\circ}C.$

Fig 3. Insertion loss ($|s_{21}|^2$) of the diode as a function of frequency; typical values



 $f = 1 \text{ MHz}; T_j = 25 \text{ }^{\circ}\text{C}.$

Fig 2. Diode capacitance as a function of reverse voltage; typical values

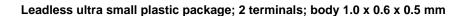


Diode zero biased and inserted in series with a 50 Ω stripline circuit.

 $T_{amb} = 25 \, ^{\circ}C.$

Fig 4. Isolation ($|s_{12}|^2$) of the diode as a function of frequency; typical values

8. Package outline



SOD882

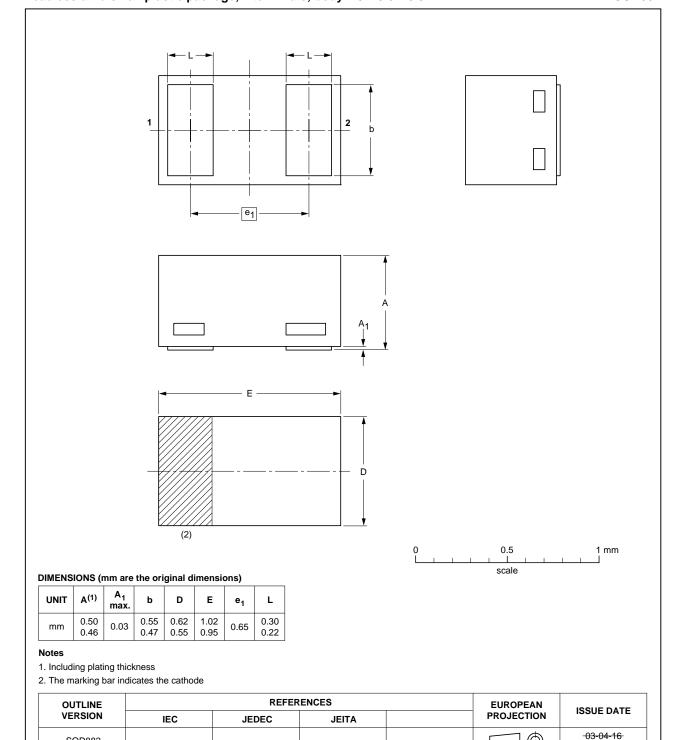


Fig 5. Package outline SOD882

03-04-17

SOD882



9. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP55L v.2	20110905	Preliminary data sheet	-	BAP55L v.1
Modifications:		of this data sheet has been r of NXP Semiconductors.	edesigned to comply w	rith the new identity
	 Legal texts 	have been adapted to the ne	w company name whe	re appropriate.
BAP55L v.1 (9397 750 14811)	20050405	Preliminary data sheet	-	-

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
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NXP Semiconductors BAP55L

Silicon PIN diode

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